

UNISONIC TECHNOLOGIES CO., LTD

MGBR20V60 Preliminary DIODE

MOS GATED BARRIER RECTIFIER

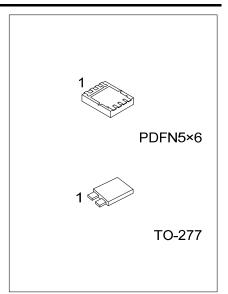
DESCRIPTION

The UTC MGBR20V60 is a surface mount mos gated barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high current capability, etc.

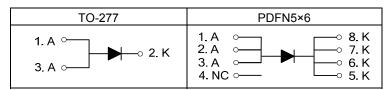
The UTC **MGBR20V60** suitable for free wheeling, high frequency inverters, polarity protection, and low voltage.

■ FEATURES

- * Very low forward voltage drop
- * High current capability
- * High surge capability
- * High efficiency



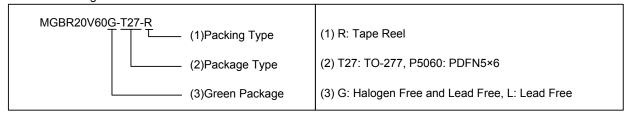
■ SYMBOL



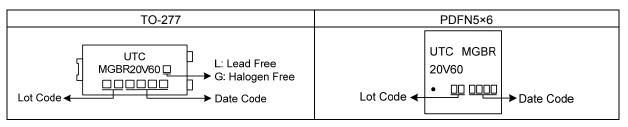
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment							Dooking		
Lead Free	Halogen Free	Package	1	2	3	4	5	6	7	8	Packing	
MGBR20V60L-T27-R	MGBR20V60G-T27-R	TO-277	Α	Κ	Α	-	-	-	-	-	Tape Reel	
MGBR20V60L-P5060-R	MGBR20V60G-P5060-R	PDFN5×6	Α	Α	Α	NC	K	Κ	Κ	K	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



■ MARKING



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■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage (Note 1)	V_{RM}	60	V
Working Peak Reverse Voltage	V_{RWM}	60	V
Peak Repetitive Reverse Voltage	everse Voltage V _{RRM}		V
Average Rectified Output Current T _C =125°C	lo	20	Α
Non-Repetitive Peak Forward Surge Current 8.3ms		200	۸
Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	200	А
Operating Junction Temperature	TJ	-65 ~ + 150	°C
Storage Temperature	T _{STG}	-65 ~ + 150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA (Note)

PARAMETER		SYMBOL	RATINGS	UNIT
Lungtion to Ambient	TO-277	0	73	°C/W
Junction to Ambient	PDFN5×6	θ_{JA}	72	°C/W
lunation to Coop	TO-277	0	13	°C/W
Junction to Case	PDFN5×6	θ_{JC}	3.4	°C/W

Note: Mounted on an FR4 PCB, single-sided copper, with 100 cm² copper pad area.

■ ELECTRICAL CHARACTERISTICS (T_A =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA	60			V
Farmend Vallege Dage	VEM	I _F =20A, T _C =25°C			0.60	V
Forward Voltage Drop		I _F =20A, T _C =125°C			0.55	V
Peak Reverse Current at Rated DC		V _R =60V, T _C =25°C			500	μΑ
Blocking Voltage (Note 1)	I _{RM}	V _R =60V, T _C =125°C			50	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

^{2.} Thermal resistance junction to case mounted on heatsink.

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